

2SD1275, 2SD1275A

Silicon NPN triple diffusion planar type Darlington

For power amplification

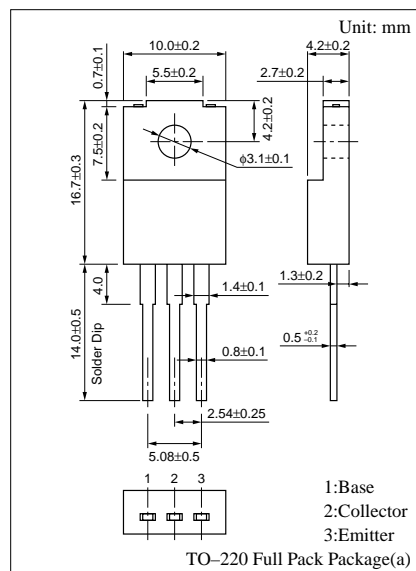
Complementary to 2SB0949 (2SB949) and 2SB0949A (2SB949A)

■ Features

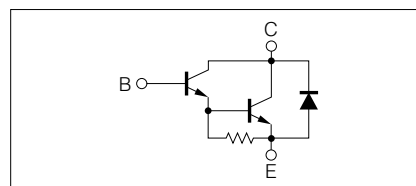
- High forward current transfer ratio h_{FE}
- High-speed switching
- Full-pack package which can be installed to the heat sink with one screw

■ Absolute Maximum Ratings (T_C=25°C)

Parameter		Symbol	Ratings	Unit
Collector to base voltage	2SD1275	V_{CBO}	60	V
	2SD1275A		80	
Collector to emitter voltage	2SD1275	V_{CEO}	60	V
	2SD1275A		80	
Emitter to base voltage		V_{EBO}	5	V
Peak collector current		I_{CP}	4	A
Collector current		I_C	2	A
Collector power dissipation	$T_C=25^{\circ}\text{C}$	P_C	35	W
	$T_a=25^{\circ}\text{C}$		2	
Junction temperature		T_j	150	$^{\circ}\text{C}$
Storage temperature		T_{stg}	-55 to +150	$^{\circ}\text{C}$



Internal Connection



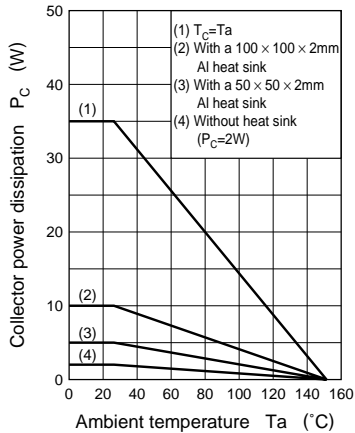
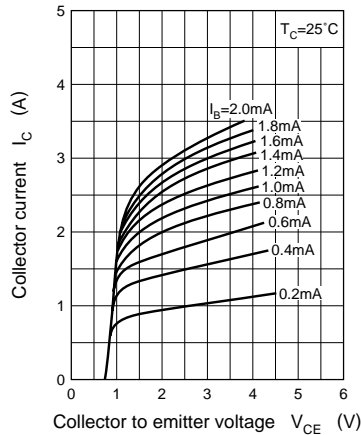
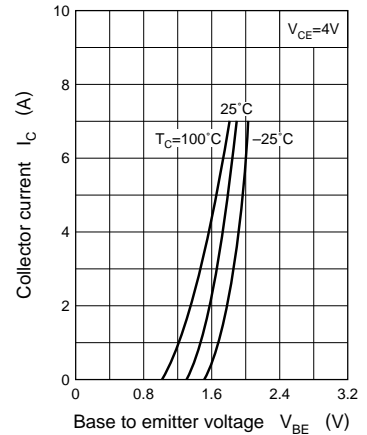
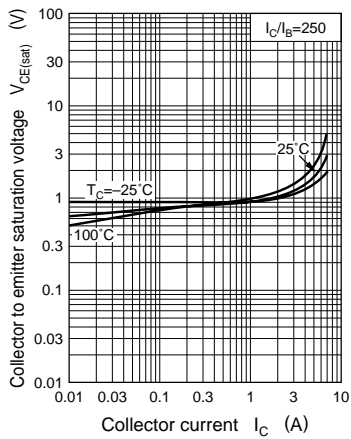
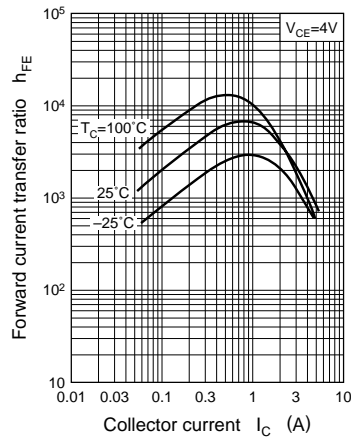
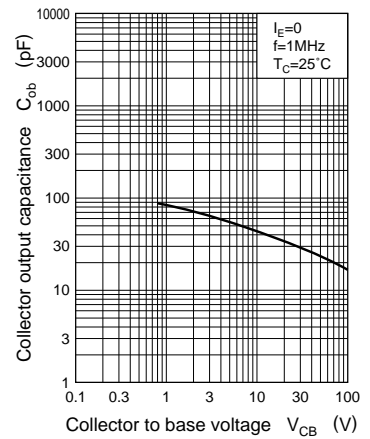
■ Electrical Characteristics (T_C=25°C)

Parameter		Symbol	Conditions	min	typ	max	Unit
Collector cutoff current	2SD1275	I_{CBO}	$V_{CB} = 60V, I_E = 0$			1	mA
	2SD1275A		$V_{CB} = 80V, I_E = 0$			1	
Collector cutoff current	2SD1275	I_{CEO}	$V_{CE} = 30V, I_B = 0$			2	mA
	2SD1275A		$V_{CE} = 40V, I_B = 0$			2	
Emitter cutoff current		I_{EBO}	$V_{EB} = 5V, I_C = 0$			2	mA
Collector to emitter voltage	2SD1275	V_{CEO}	$I_C = 30mA, I_B = 0$	60			V
	2SD1275A			80			
Forward current transfer ratio		h_{FE1}	$V_{CE} = 4V, I_C = 1A$	1000			
		h_{FE2}^*	$V_{CE} = 4V, I_C = 2A$	2000		10000	
Base to emitter voltage		V_{BE}	$V_{CE} = 4V, I_C = 2A$			2.8	V
Collector to emitter saturation voltage		$V_{CE(sat)}$	$I_C = 2A, I_B = 8mA$			2.5	V
Transition frequency		f_T	$V_{CE} = 10V, I_C = 0.5A, f = 1MHz$		20		MHz
Turn-on time		t_{on}	$I_C = 2A, I_{B1} = 8mA, I_{B2} = -8mA, V_{CC} = 50V$		0.5		μs
Storage time		t_{stg}			4		μs
Fall time		t_f			1		μs

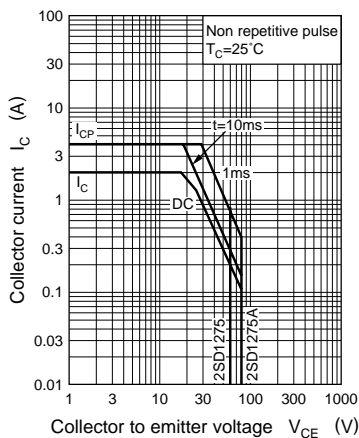
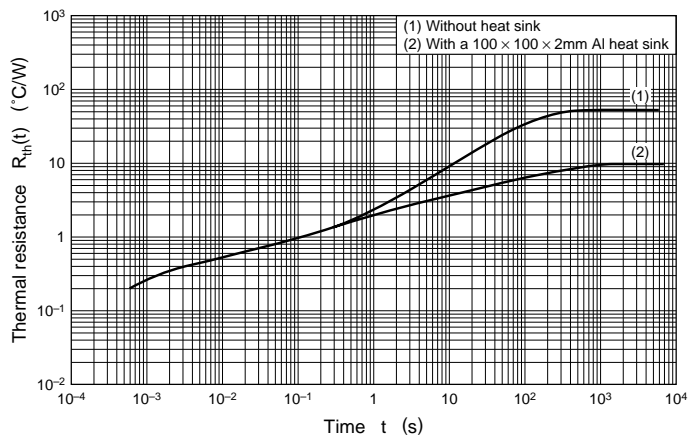
*h_{FE2} Rank classification

Rank	Q	P
h _{FE2}	2000 to 5000	4000 to 10000

Note) The part numbers in the parenthesis show conventional part number.

$P_C - T_a$  $I_C - V_{CE}$  $I_C - V_{BE}$  $V_{CE(sat)} - I_C$  $h_{FE} - I_C$  $C_{ob} - V_{CB}$ 

Area of safe operation (ASO)

 $R_{th(t)} - t$ 

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